

KY3400

30V N-Channel Mosfet

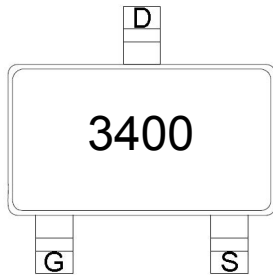
FEATURES

- $R_{DS(ON)} \leq 33m\Omega$ (21m Ω Typ.)
@ $V_{GS}=10V$
- $R_{DS(ON)} \leq 39m\Omega$ (25m Ω Typ.)
@ $V_{GS}=4.5V$
- $R_{DS(ON)} \leq 60m\Omega$ (36m Ω Typ.)
@ $V_{GS}=2.5V$

APPLICATIONS

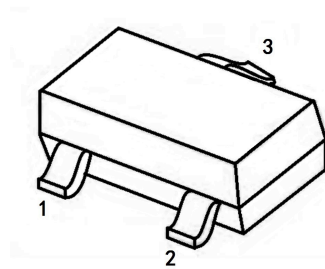
- Load/Power Switching
- Interfacing Switching

MARKING



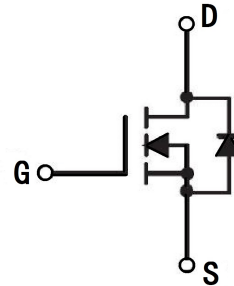
Other mark: "R0"

SOT-23



1. GATE
2. SOURCE
3. DRAIN

N-CHANNEL MOSFET



MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Max.	Units
V_{DSS}	Drain-Source Voltage	30	V
V_{GSS}	Gate-Source Voltage	± 12	V
I_D	Continuous Drain Current	5.8	A
I_{DM}	Pulsed Drain Current ^{note1}	30	A
P_D	Power Dissipation	0.35	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	$^{\circ}C/W$
T_J	Operating and Storage Temperature Range	150	$^{\circ}C$
T_{STG}	Operating and Storage Temperature Range	-55 to +150	$^{\circ}C$

MOSFET ELECTRICAL CHARACTERISTICS Ta=25 °C unless otherwise specified

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
Off Characteristic						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30	31.5	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 30V,$ $V_{GS} = 0V, T_J = 25^\circ C$	-	-	1	μA
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 12V, V_{DS} = 0V$	-	-	± 100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.7	1	1.4	V
$R_{DS(on)}$	Static Drain-Source On-Resistance <small>note2</small>	$V_{GS} = 10V, I_D = 5A$	-	21	33	m Ω
		$V_{GS} = 4.5V, I_D = 4A$	-	25	39	
		$V_{GS} = 2.5V, I_D = 3A$	-	36	60	
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$ $f = 1.0MHz$	-	-	1155	pF
C_{oss}	Output Capacitance		-	108	-	pF
C_{rss}	Reverse Transfer Capacitance		-	84	-	pF
Q_g	Total Gate Charge	$V_{DS} = 15V, I_D = 5.8A,$ $V_{GS} = 4.5V, f = 1.0MHz$	-	10	-	nC
Q_{gs}	Gate-Source Charge		-	1.6	-	nC
Q_{gd}	Gate-Drain("Miller") Charge		-	3.1	-	nC
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 15V,$ $R_L = 2.7\Omega, R_{GEN} = 3\Omega$	-	-	5	ns
t_r	Turn-On Rise Time		-	-	7	ns
$t_{d(off)}$	Turn-Off Delay Time		-	-	40	ns
t_f	Turn-Off Fall Time		-	-	6	ns
Drain-Source Diode Characteristics and Maximum Ratings						
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0V, I_{SD} = 1A,$ $T_J = 25^\circ C$	-	0.8	1	V

Notes: 1. Pulse Test : Pulse Width < 300 μs , Duty Cycle $\leq 2\%$.

2. Guaranteed by design, not subject to production testing.

TYPICAL PERFORMANCE CHARACTERISTICS

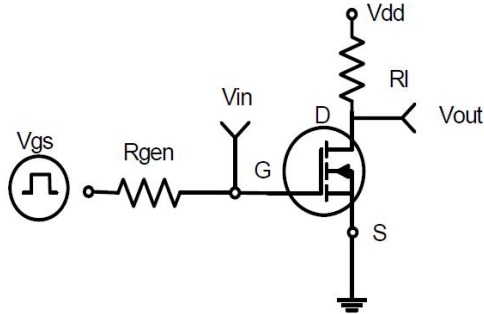


Figure 1: Switching Test Circuit

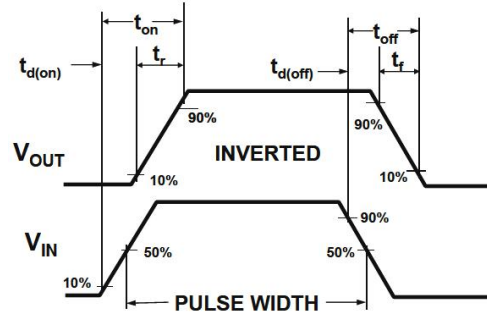


Figure 2: Switching Waveforms

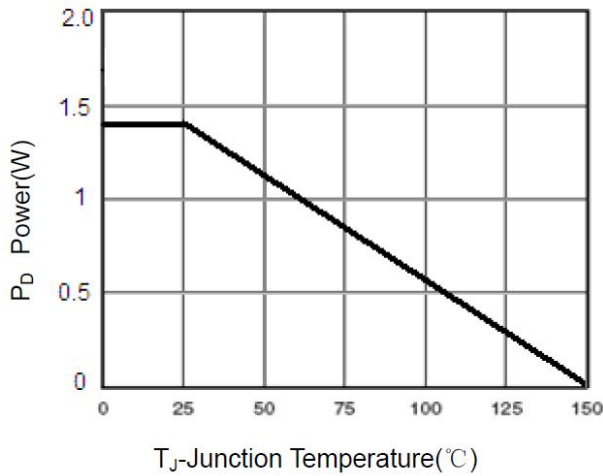


Figure 3 Power Dissipation

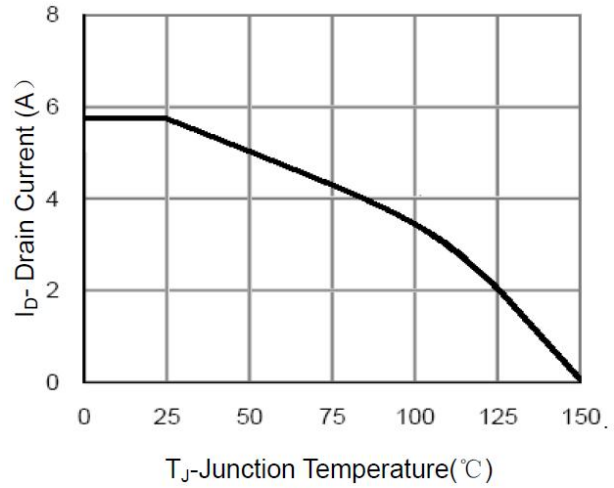


Figure 4 Drain Current

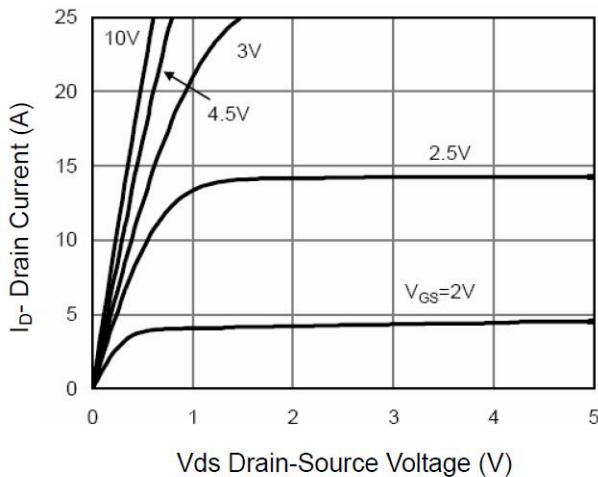


Figure 5 Output Characteristics

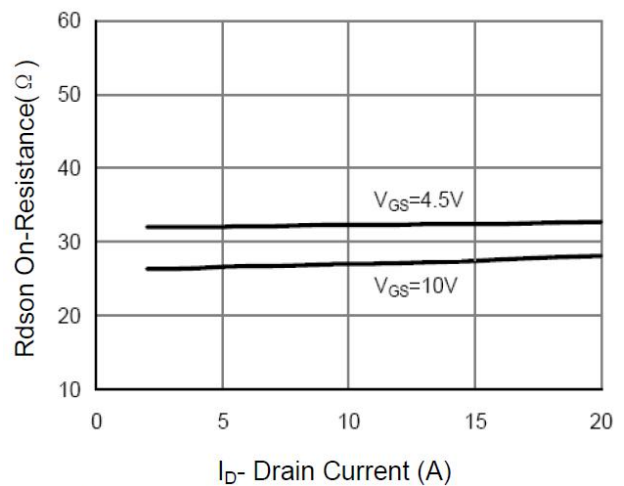


Figure 6 Drain-Source On-Resistance

TYPICAL PERFORMANCE CHARACTERISTICS (cont.)

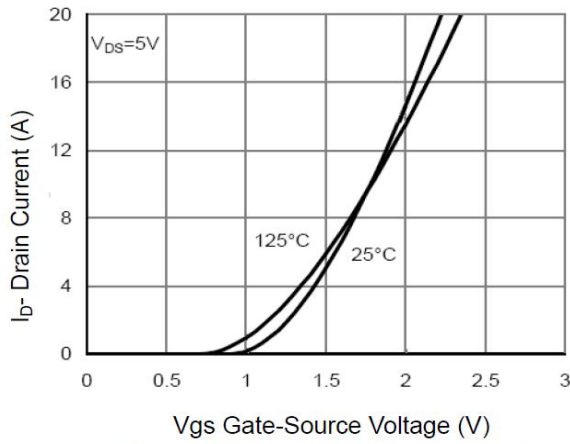


Figure 7 Transfer Characteristics

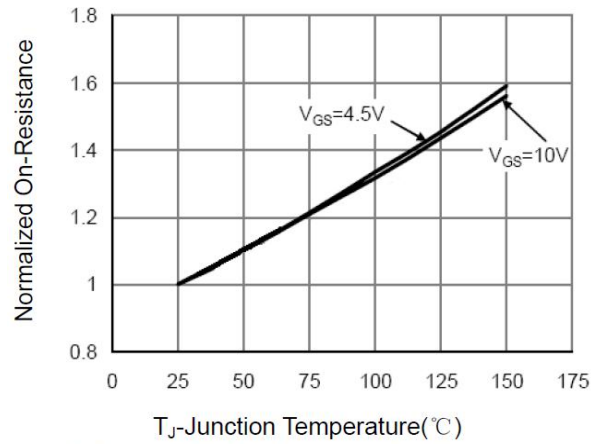


Figure 8 Drain-Source On-Resistance

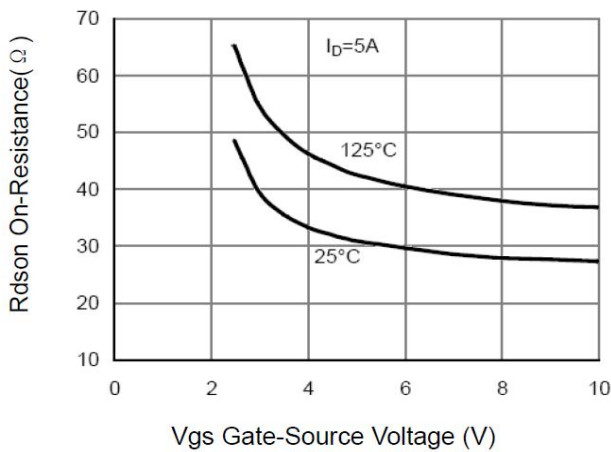


Figure 9 Rdson vs Vgs

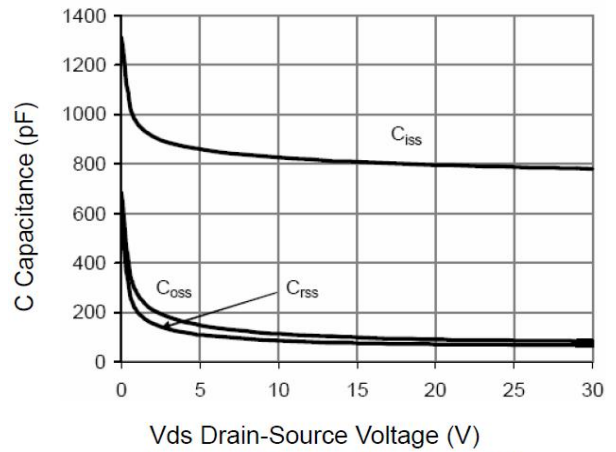


Figure 10 Capacitance vs Vds

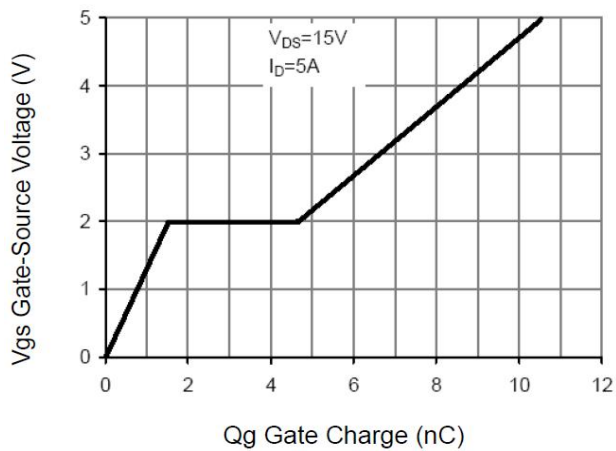


Figure 11 Gate Charge

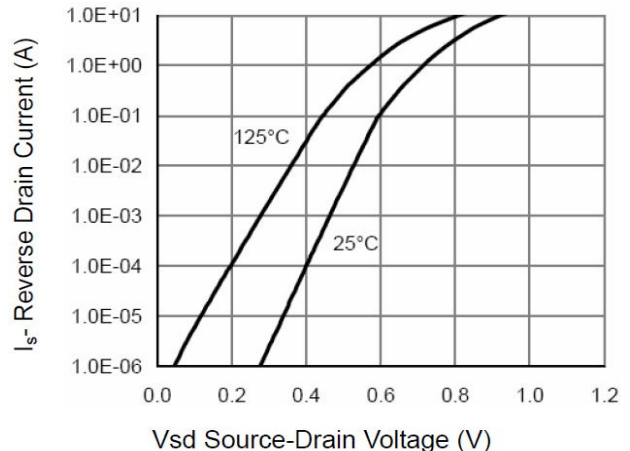
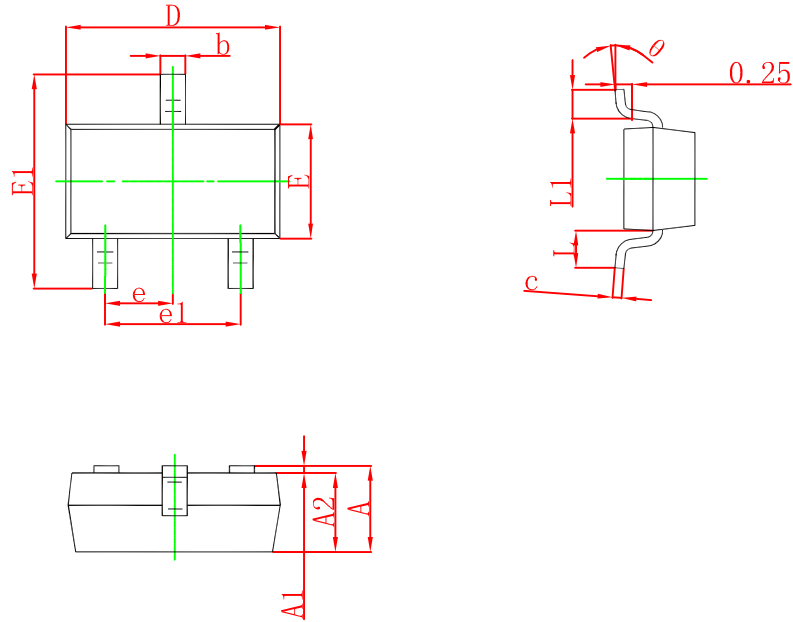


Figure 12 Source- Drain Diode Forward

SOT-23 PACKAGE OUTLINE DRAWING



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [Kang Yang](#) manufacturer:

Other Similar products are found below :

[IRFD120](#) [JANTX2N5237](#) [2SK2267\(Q\)](#) [BUK455-60A/B](#) [TK100A10N1,S4X\(S](#) [MIC4420CM-TR](#) [VN1206L](#) [NDP4060](#) [SI4482DY](#)
[IRS2092STRPBF-EL](#) [IPS70R2K0CEAKMA1](#) [SQM120N06-3M5L-GE3](#) [TK31J60W5,S1VQ\(O](#) [TK31J60W,S1VQ\(O](#) [TK16J60W,S1VQ\(O](#)
[2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [P85W28HP2F-7071](#) [NTE2384](#) [DMC2700UDMQ-7](#) [DMN2080UCB4-7](#)
[DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [IPS60R3K4CEAKMA1](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)
[STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN6022SSD-13](#) [DMN13M9UCA6-7](#) [DMTH10H4M6SPS-13](#) [IPS60R360PFD7SAKMA1](#)
[DMN2990UFB-7B](#) [SSM3K35CT,L3F](#) [IPLK60R1K0PFD7ATMA1](#) [2N7002W-G](#) [MCAC30N06Y-TP](#) [IPWS65R035CFD7AXKSA1](#)
[MCQ7328-TP](#) [SSM3J143TU,LXHF](#) [DMN12M3UCA6-7](#) [PJMF280N65E1_T0_00201](#) [PJMF380N65E1_T0_00201](#)
[PJMF280N60E1_T0_00201](#) [PJMF600N65E1_T0_00201](#) [PJMF900N65E1_T0_00201](#)